

CR12CM-12A

Thyristor

Medium Power Use

REJ03G0350-0200 Rev.2.00 Nov 30, 2007

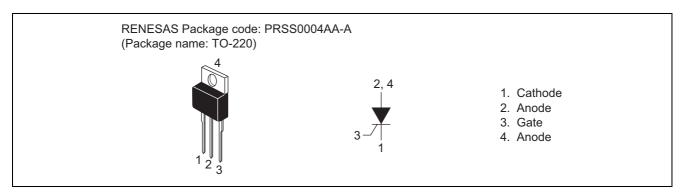
Features

• $I_{T(AV)}$: 12 A V_{DRM} : 600 V I_{GT} : 30 mA

Non-Insulated Type

Planar Passivation Type

Outline



Applications

Switching mode power supply, regulator for autocycle, motor control, heater control, and other general purpose control applications

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
	Symbol	12		
Repetitive peak reverse voltage	V_{RRM}	600	V	
Non-repetitive peak reverse voltage	V_{RSM}	720	V	
DC reverse voltage	V _{R (DC)}	480	V	
Repetitive peak off-state voltage	V_{DRM}	600	V	
DC off-state voltage	V _{D (DC)}	480	V	

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Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	18.8	Α	
Average on-state current	I _{T (AV)}	12	Α	Commercial frequency, sine half wave 180° conduction, Tc = 91°C ^{Note2}
Surge on-state current	I _{TSM}	360	Α	60Hz sine half wave 1 full cycle, peak value, non-repetitive
I ² t for fusing	l ² t	544	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	P _{G (AV)}	0.5	W	
Peak gate forward voltage	V_{FGM}	6	V	
Peak gate reverse voltage	V_{RGM}	10	V	
Peak gate forward current	I _{FGM}	2	Α	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass	_	2.0	g	Typical value

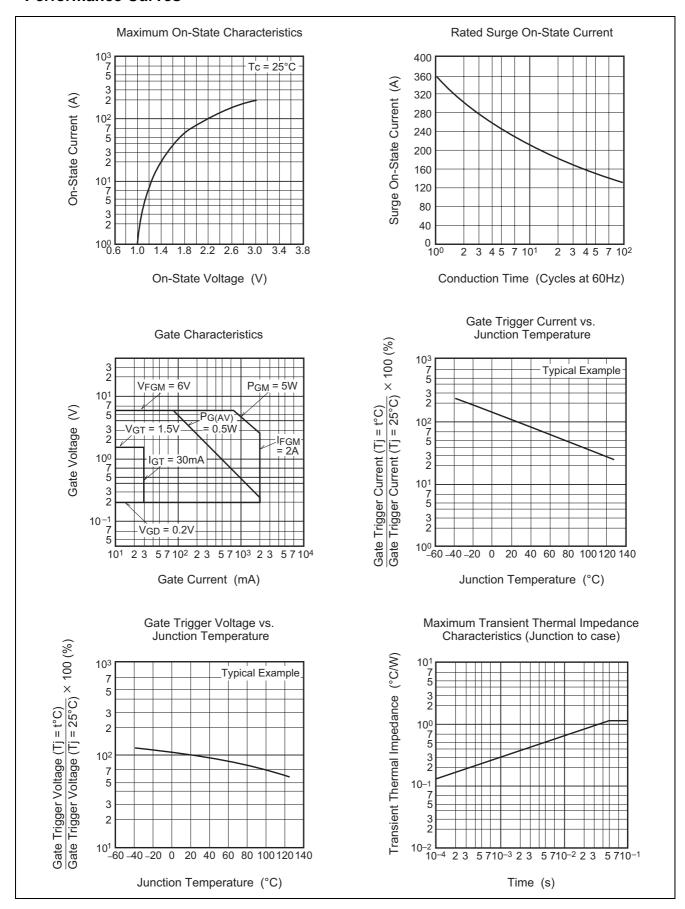
Electrical Characteristics

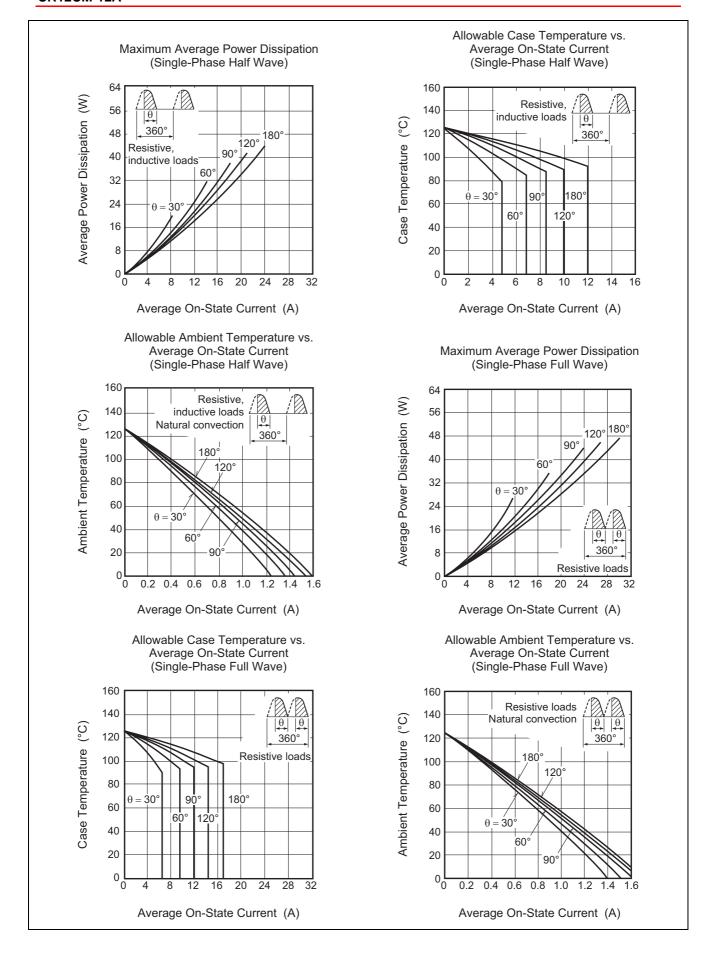
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak reverse current	I_{RRM}	_	_	2.0	mA	Tj = 125°C, V _{RRM} applied
Repetitive peak off-state current	I_{DRM}	_	_	2.0	mA	Tj = 125°C, V _{DRM} applied
On-state voltage	V_{TM}	_	_	1.6	V	$Tc = 25^{\circ}C$, $I_{TM} = 40$ A,
						instantaneous value
Gate trigger voltage	V_{GT}	_	_	1.5	V	$Tj = 25$ °C, $V_D = 6 V$, $I_T = 1 A$
Gate non-trigger voltage	V_{GD}	0.2	_	_	V	$Tj = 125$ °C, $V_D = 1/2 V_{DRM}$
Gate trigger current	I _{GT}	_	_	30	mA	$Tj = 25$ °C, $V_D = 6$ V, $I_T = 1$ A
Holding current	I _H	_	15	_	mA	Tj = 25°C, V _D = 12 V
Thermal resistance	R _{th (j-c)}	_	_	1.2	°C/W	Junction to case ^{Note1 Note2}

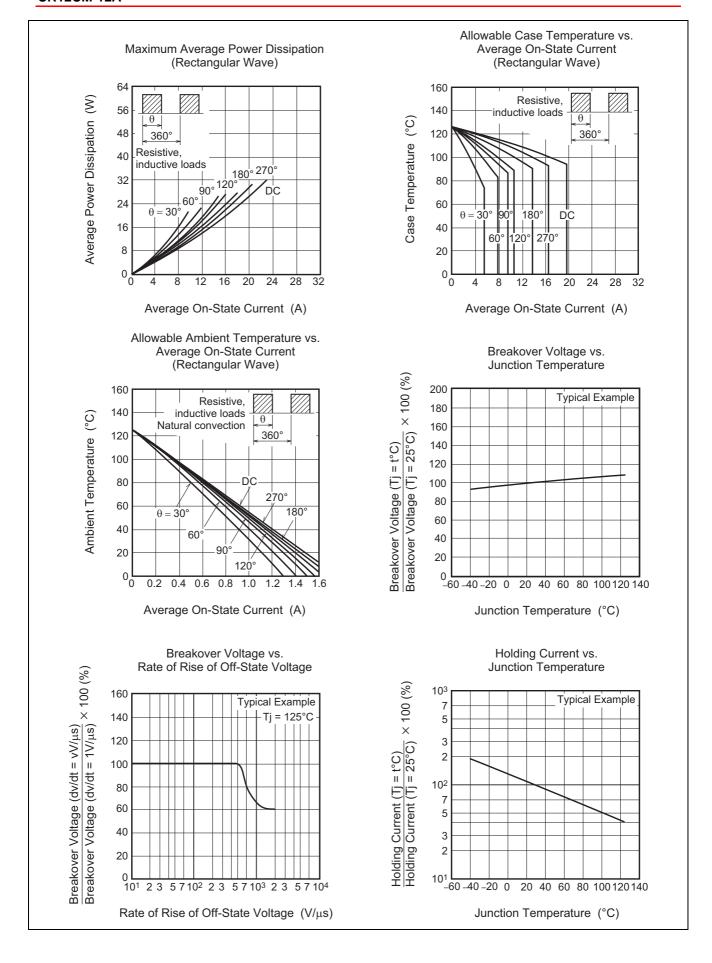
Notes: 1. The contact thermal resistance $R_{th\ (c-f)}$ in case of greasing is 1.0°C/W.

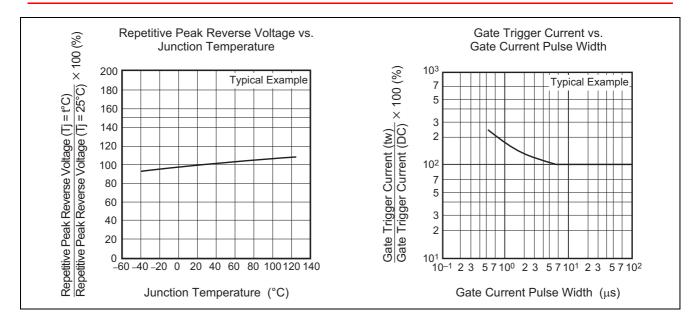
^{2.} Case temperature is measured at anode tab 1.5 mm away from the molded case.

Performance Curves

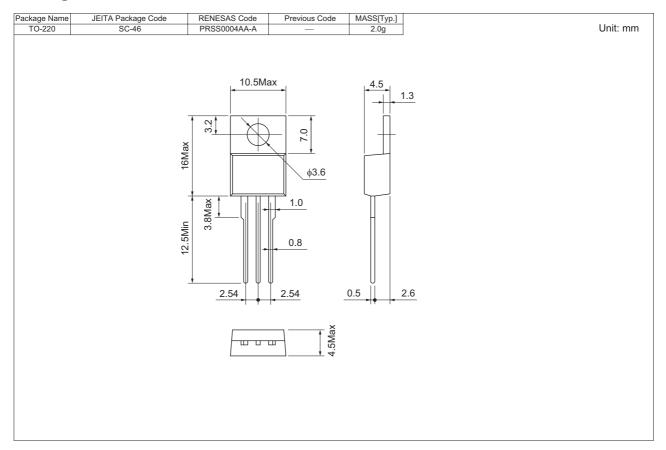








Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Vinyl sack	100	Type name	CR12CM-12A
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	CR12CM-12A-A8

Note: Please confirm the specification about the shipping in detail.

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